

## Homework #5 of 「類比積體電路導論」

作業繳交截止日期: Nov. 14, 2024 12:00 (上傳 E3 數位平台 繳交)

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本次作業共四大題, 5.1~5.4

請將作業轉成一個 PDF 檔案(file size 小於 10MB), 檔名請使用

「AIC\_HW5\_自己的學號」(例如: AIC\_HW5\_109700018), 於作業繳

交截止日期/時間前, 上傳到指定的 E3 數位平台 繳交。

Use the  $g_m$ ,  $\omega$ ,  $4kT$ ,  $\gamma$  to represent the answer of following questions.

**5.1 Calculate the input-referred noise voltage and current of Figure 1, including only the thermal noise of  $M_1$  and  $R_D$ . Neglect channel length modulation.**

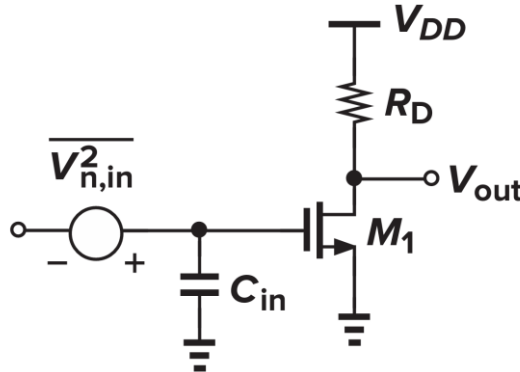


Figure 1

**5.2 Calculate the input-referred thermal noise voltage of each circuit in Figure 2.**

Assume using the long channel transistors, neglecting channel-length modulation and body effect, and ignoring the noise generated by the polysilicon gate.

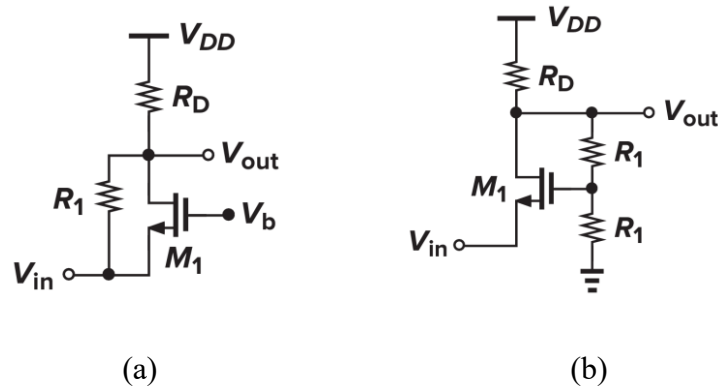


Figure 2

**5.3 Calculate the input-referred 1/f noise voltage of the source follower shown in Figure 3.**

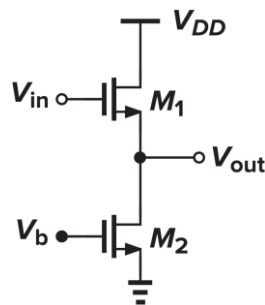


Figure 3

**5.4 Figure 4 shows a noiseless amplifier driven by a source resistance of  $R_S$ . If the amplifier can be modeled by a low-frequency gain of  $A_0$  and a single pole at  $\omega_0$ , determine the total integrated noise at the output due to  $R_S$ .**

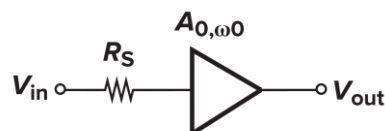


Figure 4